Ge-nanoclusters were formed by electron-beam irradiation in Ge-doped silica-on-silicon thin films. The size and density of the clusters can be controlled by the irradiation intensity and time. / Ou, Haiyan; Rørdam, Troels Peter; Rottwitt, Karsten; Grumsen, Flemming Bjerg; Horsewell, Andy.


Research output: Research - peer-review › Journal article – Annual report year: 2006